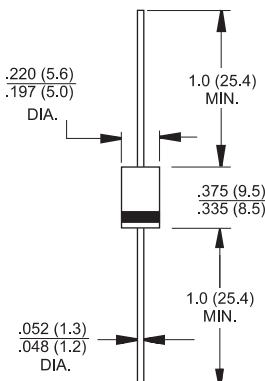




Features

- ✧ Schottky Barrier Chip
- ✧ Guard Ring Die Construction for Transient Protection
- ✧ High Current Capability
- ✧ Low Power Loss, High Efficiency
- ✧ High Surge Current Capability
- ✧ For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications

DO-201AD



Mechanical Data

- ✧ Case: Molded Plastic
- ✧ Polarity: Cathode Band
- ✧ Weight: 1.2 grams (approx.)
- ✧ Mounting Position: Any
- ✧ Marking: Type Number

Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	SR320	SR330	SR340	SR350	SR360	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	20	30	40	50	60	V
RMS Reverse Voltage	V _R (RMS)	14	21	28	35	42	V
Average Rectified Output Current (Note 1) @T _L = 95°C	I _O			3.0			A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}			80			A
Forward Voltage @I _F = 3.0A	V _{FM}		0.50		0.74		V
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C	I _{RM}			0.5 20			mA
Typical Junction Capacitance (Note 2)	C _j			250			pF
Typical Thermal Resistance Junction to Ambient	R _{θJA}			20			K/W
Operating and Storage Temperature Range	T _j , T _{STG}			-65 to +150			°C

Note: 1. Valid provided that leads are kept at ambient temperature at a distance of 9.5mm from the case.

2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

